## MG100J6ES50

## High Power Switching Applications <br> Motor Control Applications

- The electrodes are isolated from case.
- High input impedance.
- 6 IGBTs built into 1 package.
- Enhancement-mode.
- High speed: $\mathrm{t}_{\mathrm{f}}=0.30 \mu \mathrm{~s}(\mathrm{Max})(\mathrm{IC}=100 \mathrm{~A})$

$$
t_{r r}=0.15 \mu \mathrm{~s}(\mathrm{Max})\left(\mathrm{I}_{\mathrm{F}}=100 \mathrm{~A}\right)
$$

- Low saturation voltage

$$
: \mathrm{VCE}(\text { sat })=2.70 \mathrm{~V}(\mathrm{Max})(\mathrm{IC}=100 \mathrm{~A})
$$

## Equivalent Circuit



Weight: 505g (Typ.)


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Maximum Ratings ( $\mathbf{T a}=25^{\circ} \mathrm{C}$ )

| Characteristic |  | Symbol | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Collector-emitter voltage |  | $V_{\text {CES }}$ | 600 | V |
| Gate-emitter voltage |  | $V_{\text {GES }}$ | $\pm 20$ | V |
| Collector current | DC | $\mathrm{I}_{C}$ | 100 | A |
|  | 1 ms | $\mathrm{I}_{\mathrm{CP}}$ | 200 |  |
| Forward current | DC | $\mathrm{I}_{\mathrm{F}}$ | 100 | A |
|  | 1 ms | IFM | 200 |  |
| Collector power dissipation ( $\mathrm{Tc}=25^{\circ} \mathrm{C}$ ) |  | $\mathrm{P}_{\mathrm{C}}$ | 450 | W |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $\mathrm{T}_{\text {stg }}$ | $-40 \sim 125$ | ${ }^{\circ} \mathrm{C}$ |
| Isolation voltage |  | $V_{\text {Isol }}$ | $\begin{gathered} 2500 \\ \text { (AC } 1 \mathrm{~min} .) \end{gathered}$ | V |
| Screw torque (Terminal / mounting) |  | - | $2 / 3$ | $N \cdot m$ |

Electrical Characteristics ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristic |  | Symbol | Test Condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Gate leakage current |  | $I_{\text {GES }}$ | $\mathrm{V}_{\mathrm{GE}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{CE}}=0$ | - | - | $\pm 500$ | nA |
| Collector cut-off current |  | ICES | $\mathrm{V}_{\mathrm{CE}}=600 \mathrm{~V}, \mathrm{~V}_{\mathrm{GE}}=0$ | - | - | 1.0 | mA |
| Gate-emitter cut-off voltage |  | $\mathrm{V}_{\mathrm{GE}}$ (off) | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | 5.0 | 7.0 | 8.0 | V |
| Collector-emitter saturation voltage |  | $\mathrm{V}_{\text {CE }}$ (sat) | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~A}, \mathrm{~V}_{\mathrm{GE}}=15 \mathrm{~V}$ | - | 2.10 | 2.70 | V |
| Input capacitance |  | $\mathrm{C}_{\text {ies }}$ | $\begin{aligned} & V_{C E}=10 V, V_{G E}=0, \\ & f=1 \mathrm{MHz} \end{aligned}$ | - | 9000 | - | pF |
| Switching time | Turn-on delay time | $\mathrm{t}_{\mathrm{d}}$ (on) | Inductive load $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=300 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=100 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{GE}}= \pm 15 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{G}}=13 \Omega \end{aligned}$ <br> (Note 1) | - | 0.08 | 0.16 | $\mu \mathrm{s}$ |
|  | Rise time | $\mathrm{t}_{\mathrm{r}}$ |  | - | 0.12 | 0.24 |  |
|  | Turn-on time | $\mathrm{t}_{\text {on }}$ |  | - | 0.40 | 0.80 |  |
|  | Turn-off delay time | $t_{d}$ (off) |  | - | 0.20 | 0.40 |  |
|  | Fall time | $\mathrm{t}_{\mathrm{f}}$ |  | - | 0.15 | 0.30 |  |
|  | Turn-off time | $\mathrm{t}_{\text {off }}$ |  | - | 0.50 | 1.00 |  |
| Forward voltage |  | $V_{F}$ | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~A}, \mathrm{~V}_{\mathrm{GE}}=0$ | - | 2.30 | 3.00 | V |
| Reverse recovery time |  | $\mathrm{t}_{\mathrm{rr}}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=100 \mathrm{~A}, \mathrm{~V}_{\mathrm{GE}}=-10 \mathrm{~V} \\ & \mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{s} \end{aligned}$ | - | 0.08 | 0.15 | $\mu \mathrm{s}$ |
| Thermal resistance |  | $\mathrm{R}_{\text {th ( }} \mathrm{j}$ - c ) | Transistor | - | - | 0.28 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | Diode | - | - | 0.69 |  |

Note 1: Switching time test circuit \& timing chert








$\mathrm{t}_{\mathrm{off}}, \mathrm{t}_{\mathrm{d}}(\mathrm{off}), \mathrm{t}_{\mathrm{f}}-\mathrm{I}_{\mathrm{C}}$










